

Application Note 26 Ultra High-Speed Microcontroller Memory Interface Timing

www.maxim-ic.com

INTRODUCTION

The Ultra High-Speed Microcontroller family, including the DS89C420, incorporates a unique 1-clock-per-machine cycle core and varying amounts of Flash memory and internal MOVX SRAM. Although this makes it possible to design a complete system with no external memory components, some applications may need to access additional program and/or data memory via the high-speed external memory bus. The devices in this family support multiple memory access modes to allow operation at the fastest speed with the slowest (and, hence, least expensive) memory devices.

The design of any memory system relies on any number of common sense rules. Always keep high-speed address lines short to minimize transmission line effects. Keep loading on any memory signals low by minimizing the number of loads and/or using buffers. Always use adequate decoupling on the microcontroller, demultiplexing latch, and memory devices; this is especially important when designing with a very high-speed microcontroller such as the DS89C420.

These specifications assume approximately equal capacitive load on the signals specified. If, however, any signal is connected to additional loads, then additional margins should be used in the critical path analysis, and appropriate memory speed selected. For otherwise unconventional devices, it might be wise to confirm other important timing parameters (such as data setup before write active) as part of the design evaluation. Buffers can be used to minimize the effects of heavy bus loading.

This application note is an aid to the system architects in selecting the correct memory type and speed to meet their design criteria. It discusses design suggestions and timing considerations for the various external memory addressing modes. The calculations in this application note are based on the best data available at the time it was composed. Please check the corresponding data sheets for the most updated information on any device.

BUS MODES

When interfacing to external memory the architect will have to select one of the five supported bus modes, each of which has a significant affect on external memory timing. Each bus mode uses different configurations of the memory signals connected to P0 and P2. The variety of new modes (page modes) allows the external memory interface to operate at different speeds, almost all of them faster than the standard 8051 memory interfacing scheme. The speed improvement is achieved primarily by rearranging the external bus structure of the microcontroller such that the address LSB and data bus have a direct (i.e., not through the latch) connection to the memory devices. This means that the address MSB, held in the '373 latch, need only be updated when the address transitions across a 256-byte boundary. Once the MSB is latched, memory accesses will execute at their fastest speed (page hit). The page modes incur a 2-cycle penalty when updating the address latch during a boundary crossing (page miss), but otherwise operate faster than the traditional 8051 architecture.

1 of 10 013002

Most applications will use either non-page mode (for compatibility with the traditional 8051), or page mode 1, 1-cycle (for fastest speed possible). These buses are typically hard-wired in the finished application and do not change dynamically. The bus modes are as follows:

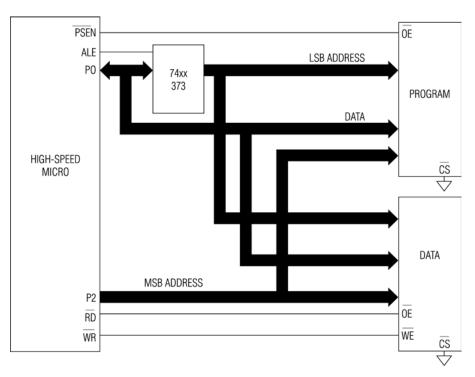
- Non-Page Mode
- Page Mode 1 (1-cycle)
- Page Mode 1 (2-cycle)
- Page Mode 1 (4-cycle)
- Page Mode 2

Note that page mode operation is enabled via software. This means that in order to utilize any of the page modes, execution must first commence from the internal Flash memory and enable page mode operation. This is because the microcontroller defaults to non-page mode following any reset.

Non-Page Mode

Figure 1 shows the traditional 8051 memory interfacing scheme, also referred to as non-page mode. Port 2 of the microcontroller displays A15–A8 of the address, while Port 0 displays either A7–0 or data D7–D0 depending on which part of the memory cycle is being executed. This is the default mode of the microcontroller following a reset. In this example, both program and data memory devices are included in the system. Members of this family interface with external memories via a multiplexed bus to reduce pin count. As a result, an external latch such as a 74ACQ373 or 74ACQ573 with minimal propagation delay is necessary to demultiplex the address and/or data signals to the memories. The contents of the latch change every memory cycle, so the type and logic family must be carefully chosen as its propagation delay is in the critical timing path of the external memory interface.

Figure 1. NON-PAGE MODE MEMORY INTERFACE

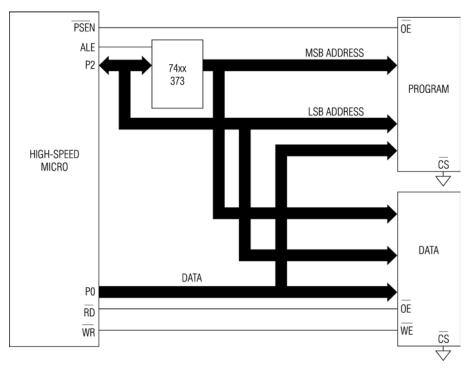


External memory timing in this mode is almost identical to the 4-clock-per-machine cycle DS87C520. In this mode there are no page misses or hits. Internal Flash or SRAM accesses take one system clock cycle regardless of Stretch Cycle settings, and external MOVC or code fetches take four system clock cycles. External MOVX operations require a minimum of four system clock cycles.

Page Mode 1 (1-Cycle)

This is the fastest external addressing mode. In this mode internal code fetches take as little as one clock cycle. The speed enhancements are possible because the address MSB is latched, allowing the data and address LSB to be connected directly to the memory device. An extra cycle is inserted during page misses to allow time to update the latch with the new address MSB. The 2- and 4-cycle versions of this mode are similar to page mode 1 (1-cycle), except that external memory operations are extended to accommodate slower devices. The sections of this document that deal with selecting program and data memory access speeds assume a page hit cycle, as it is faster and more time critical than page miss cycles. Timing calculations for page hits will also work for page misses.



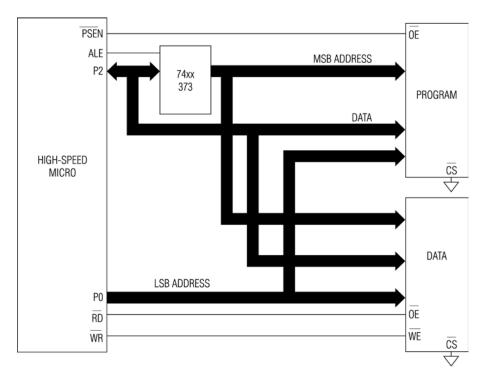


MEMORY ACCESS	SYSTEM CLOCK CYCLES PER PAGE HIT (1-Cycle/2-Cycle/4-Cycle)	SYSTEM CLOCK CYCLES PER PAGE MISS (1-Cycle/2-Cycle/4-Cycle)		
Internal Flash/MOVX	1/1/1	1/1/1		
External MOVC/Code Fetch	1/2/4	2/4/8		
External MOVX	2/2/4 (more if Stretch cycles used)	2/4/8 (more if Stretch cycles used)		

Page Mode 2

This external addressing mode multiplexes the address MSB and data on P2, and places the LSB of the address on P0. This bus configuration increases the speed of external code fetches only, so the timing of external MOVX accesses is identical to non-page mode.

Figure 3. PAGE MODE 2 MEMORY INTERFACE



MEMORY ACCESS	SYSTEM CLOCK CYCLES PER PAGE HIT	SYSTEM CLOCK CYCLES PER PAGE MISS
Internal Flash/MOVX	1	1
External MOVC/Code Fetch	2	4
External MOVX	4 (more if Stretch cycles used)	4 (more if Stretch cycles used)

SELECTING PROGRAM MEMORY ACCESS SPEEDS

This microcontroller was designed to interface to typical program memory technologies such as EPROM, Flash memory, or SRAM. Several critical AC timing characteristics, discussed below, must be considered when selecting a memory device. The selection of a particular device is often an iterative process, juggling cost, availability, and the timing parameters of the memory, dictated by the operating frequency of the microcontroller. The following tables relate memory device timing specifications to their microcontroller counterpart. The system clock frequency used in the tables is the external clock frequency multiplied by any crystal multiplier factors, i.e., an external clock frequency of 10MHz with the 2X multiplier enabled would have a system clock frequency of 20MHz. All of the timings are examples for common frequencies; exact values for other frequencies can be calculated using the equations given in the data sheet. The timings for page modes assume a page hit, the most time critical sequence. In general the memory timing parameter must be less than the corresponding microcontroller value to be suitable.

1. Access time of the memory from valid address. In the microcontroller this is typically t_{AVIV} , and in the memory device it is t_{ACC} or t_{AA} . This parameter represents the time required for the memory device to decode the 16-bit address and place the data on the data bus. Depending on the mode, the critical

timing is dependent on either port 0 or port 2. For non-page mode, the multiplexing of D7–0 and A7–0 on port 0 means that the propagation delay of the latch must be added to the equation. This requires that the memory be slightly faster than the corresponding microcontroller timing specification.

Table 1. t_{AVIV} TIMINGS

SYSTEM CLOCK (MHz)	t _{CLCL} (ns)	NON- PAGE*	PAGE MODE 1 (1-Cycle)	PAGE MODE 1 (2-Cycle)	PAGE MODE 1 (4-Cycle)	PAGE MODE 2
		$t_{AVIV}+t_{PROP}$	$t_{\rm AVIV2}$	$t_{ m AVIV2}$	$t_{ m AVIV2}$	$t_{ m AVIV}$
33	30.30	62.41	25.30	40.45	101.06	86.06
25	40.00	91.50	35.00	55.00	135.00	120.00
11.0592	90.42	242.77	85.42	130.63	311.48	296.48
5	200.00	571.50	195.00	295.00	695.00	680.00

^{*}Includes t_{PROP} of 74ACQ373 latch.

2. Access time of the memory from output enable valid. In the microcontroller this is typically t_{PLIV} , and in the memory device it is t_{OE} . This parameter represents the time required for the chip to activate its outputs from a disabled state. In most memory configurations the \overline{PSEN} signal serves as the output enable signal for external program memory devices. A valid address must be present prior to the chip enable(s) going active for this parameter to be valid.

Table 2. t_{PLIV} TIMINGS

SYSTEM CLOCK (MHz)	t _{CLCL} (ns)	NON- PAGE*	PAGE MODE 1 (1-Cycle)	PAGE MODE 1 (2-Cycle)	PAGE MODE 1 (4-Cycle)	PAGE MODE 2
33	30.30	25.30	25.30	25.30	55.61	25.30
25	40.00	85.42	85.42	85.42	175.84	85.42
11.0592	90.42	25.30	25.30	25.30	55.61	25.30
5	200.00	85.42	85.42	85.42	175.84	85.42

3. Data float (bus release) time. This parameter represents the amount of time that the memory device will continue to drive the bus after the output enable signal has been de-asserted. This parameter is important in non-page mode and page mode 2 because during each cycle the bus must switch between data and address. This may be a critical parameter at high system clock speeds, and the designer should be sure that t_{DF} is always less than the microcontroller parameter t_{PXIZ}.

Table 3. t_{PXIZ} TIMINGS

SYSTEM CLOCK (MHz)	t _{CLCL} (ns)	NON-	PAGE MODE 1 (1-Cycle)	PAGE MODE 1 (2-Cycle)	PAGE MODE 1 (4-Cycle)	PAGE MODE 2
33	30.30	4.0	N/A	N/A	N/A	4.0
25	40.00	4.0	N/A	N/A	N/A	4.0
11.0592	90.42	4.0	N/A	N/A	N/A	4.0
5	200.00	4.0	N/A	N/A	N/A	4.0

Signal timings for memory devices vary widely between device types. A typical sampling of memory device timings is shown below.

Table 4. SAMPLING OF CRITICAL MEMORY TIMING PARAMETERS FOR VARIOUS MEMORY TECHNOLOGIES

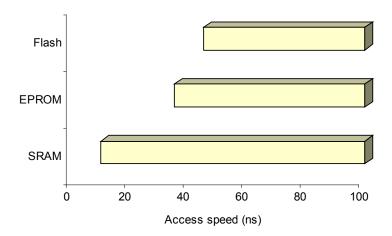
K6R1008C1C (SRAM)	-10	-15	-20
t_{ACC}	10	15	20
$t_{ m OE}$	5	7	9
$t_{ m OHZ}$ / $t_{ m DF}$	5	7	9

M27C1001-35 (EPROM)	-35	-45	-60
t_{ACC}	35	45	60
$t_{ m OE}$	25	25	30
$t_{ m OHZ}$ / $t_{ m DF}$	25	25	30

Am29F010B-45 (Flash)	-45	-70	-90
t_{ACC}	45	70	90
$t_{ m OE}$	25	30	35
$t_{ m OHZ}$ / $t_{ m DF}$	10	15	20

Comparing these devices against the times shown above, one can select the appropriate memory device. As a general rule of thumb, the access time from valid address is usually the critical timing parameter, but the system designer is encouraged to validate all of the memory timing parameters. The graph below shows the relative access speeds of memory devices. In general, SRAM is required to run at 33MHz, but below 25MHz EPROM or Flash technologies will work.

Figure 4. REPRESENTATION OF ACCESS TIMES OF MEMORY TYPES



The following table is a convenient summary of required memory access timings for various system clock frequencies for page mode (1-cycle), and non-page mode for common microcontroller frequencies. This is a good starting point for selecting a memory device.

Table 5. RECOMMENDED ACCESS TIME OF PROGRAM MEMORY DEVICE BY FREQUENCY

	MAXIMUM ACCESS TIME OF PROGRAM MEMORY DEVICE			
System Clock Frequency (MHz)	Non-Page Mode	Page Mode 1 (1-Cycle)		
33	55	20		
29.4912	70	20		
25	70	35		
22.1184	90	35		
20	90	35		
19.8	120	35		
18.432	120	45		
16.8	120	45		
16	150	55		
14.746	150	55		
14.318	150	55		
12	200	55		
11.059	200	70		

USING BUS MODES TO IMPROVE SYSTEM PERFORMANCE

Although page mode 1, 1-cycle is the fastest external addressing mode, there are situations in which overall system speed can be enhanced by utilizing one of the other page modes. These situations involve the use of internal and external program memory in the same design. Suppose that the system designer wants to run the microcontroller at maximum speed with a page mode 1, 1-cycle bus but use nonvolatile (EPROM of Flash) memory. From the above tables, it can be seen that the fastest EPROM access time is 35ns, which would restrict the maximum system clock speed to 25MHz.

An alternative would be to segment the software and relegate the most time critical portions to internal memory. Then use one of the slower bus modes such as page mode 1, 2-cycle or 4-cycle to interface to the external memory. The microcontroller could then run at its maximum system clock frequency; internal code execution would occur at full speed, and infrequently occurring external accesses would be performed at a slightly slower speed. This allows the system to run both internal and external code at its fastest speed at the same time.

Selecting Data Memory Access Speeds

Data memory interfacing is similar to program memory interfacing, with the exception of the use of RD and \overline{WR} signals. The following tables relate memory device timing specifications to their microcontroller counterpart. The system clock frequency used in the tables is the external clock frequency multiplied by any crystal multiplier factors, e.g., an external clock frequency of 10MHz with the 2X multiplier enabled would have a system clock frequency of 20MHz. All of the timings are examples for common frequencies; exact values for other frequencies can be calculated using the equations given in the data sheet.

The stretch cycle feature allows the microcontroller to automatically lengthen or stretch external data memory (MOVX) accesses to accommodate slower external memories and peripherals. This is especially important when the microcontroller will be used to upgrade slower traditional 8051-based systems. Additionally, there are a variety of memory-mapped peripherals such as LCD displays or UARTs that are

not fast enough to keep up with the microcontroller. Internal MOVX and MOVC operations are always performed in 1-clock cycle, regardless of the stretch cycle settings. A stretch value of zero is assumed, allowing external data memory to run at its fastest speed.

All members of this device family default to the use of one stretch cycle for MOVX instructions. For maximum speed, application software can write to certain Special Function Register (SFR) bits and cause the MOVX instructions to operate with zero stretch cycles. Stretch cycles are covered in more detail in the corresponding data sheet and the DS89C420 User's Guide.

1. MOVX access time of the memory from valid address. In the microcontroller this is typically t_{AVDV}, and in the memory device it is t_{ACC}. This parameter represents the finite amount of time required for the memory device to decode the 16-bit address and place the data on the data bus. Depending on the mode, the critical timing is dependent on either port 0 or port 2. For non-page mode, the multiplexing of D7–0 and A7–0 on port 0 means that the propagation delay of the latch must be added to the equation. This requires that t_{AVDV} be slightly less than t_{ACC}.

Table 6. t_{AVDV} TIMINGS

SYSTEM CLOCK (MHz)	t _{CLCL} (ns)	NON-PAGE*	PAGE MODE 1 (1-Cycle)	PAGE MODE 1 (2-Cycle)	PAGE MODE 1 (4-Cycle)	PAGE MODE 2
		$t_{AVDV} + t_{PROP}$	t_{AVDV2}	t_{AVDV2}	t_{AVDV2}	$t_{ m AVDV}$
33	30.30	62.41	25.30	40.45	101.06	86.06
25	40.00	91.50	35.00	55.00	135.00	120.00
11.0592	90.42	242.77	85.42	130.63	311.48	296.48
5	200.00	571.50	195.00	295.00	695.00	680.00

^{*}Includes t_{PROP} of 74ACQ373 latch.

2. Access time of the memory from output enable valid. In the microcontroller this is typically t_{RLDV} , and in the memory device it is t_{OE} . This parameter represents the time required for the memory device to activate its outputs from a disabled state. In MOVX operations the \overline{RD} signal serves as the output enable signal for external program memory devices. A valid address must be present prior to the chip enable(s) going active for this parameter to be valid.

Table 7. t_{RIDV} TIMINGS

SYSTEM CLOCK (MHz)	t _{CLCL} (ns)	NON-PAGE*	PAGE MODE 1 (1-Cycle)	PAGE MODE 1 (2-Cycle)	PAGE MODE 1 (4-Cycle)	PAGE MODE 2
33	30.30	55.61	25.30	25.30	55.61	55.61
25	40.00	75.00	35.00	35.00	75.00	75.00
11.0592	90.42	175.84	85.42	85.42	175.84	175.84
5	200.00	395.00	195.00	195.00	395.00	395.00

3. RD and WR pulse width. This parameter represents the amount of time that the RD and WR strobes are asserted. In the microcontroller this is typically t_{RLRH} or t_{WLWH}. This parameter is important because SRAMs have minimum specifications for these parameters that must be guaranteed at high speeds.

Table 8. t_{RLRH} / t_{WLWH} TIMINGS

	TABLET TEATH						
SYSTEM CLOCK (MHz)	t _{CLCL} (ns)	NON-PAGE*	PAGE MODE 1 (1-Cycle)	PAGE MODE 1 (2-Cycle)	PAGE MODE 1 (4-Cycle)	PAGE MODE 2	
33	30.30	55.61	25.30	25.30	55.61	55.61	
25	40.00	75.00	35.00	35.00	75.00	75.00	
11.0592	90.42	175.84	85.42	85.42	175.84	175.84	
5	200.00	395.00	195.00	195.00	395.00	395.00	

4. Data float (bus release) time. This parameter represents the amount of time that the memory device will continue to drive the bus after the output enable signal has been de-asserted. This parameter is important in non-page mode and page mode 2 because during each cycle the bus must switch between data and address. This can be a critical parameter at high system clock speeds, and the designer should be sure that t_{DF} is always less than the microcontroller parameter t_{PXIZ}.

Table 9. t_{RHDZ} TIMINGS

SYSTEM CLOCK (MHz)	t _{CLCL} (ns)	NON-PAGE*	PAGE MODE 1 (1-Cycle)	PAGE MODE 1 (2-Cycle)	PAGE MODE 1 (4-Cycle)	PAGE MODE 2
33	30.30	4.0	N/A	N/A	N/A	4.0
25	40.00	4.0	N/A	N/A	N/A	4.0
11.0592	90.42	4.0	N/A	N/A	N/A	4.0
5	200.00	4.0	N/A	N/A	N/A	4.0

Because program memory and data memory accesses have similar timings (when no stretch cycles are selected), Table 5 provides a convenient summary of required MOVX memory access timings for various system clock frequencies for page mode (1-cycle), and non-page mode for common microcontroller frequencies. This is a good starting point for selecting a data memory device.